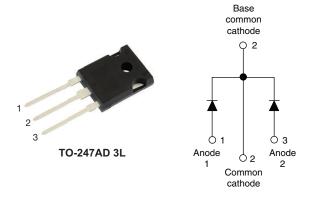


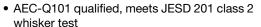
Ultrafast Rectifier, 2 x 30 A FRED Pt®



PRODUCT SUMMARY				
Package	TO-247AD 3L			
I _{F(AV)}	2 x 30 A			
V_{R}	600 V			
V _F at I _F	1.75 V			
t _{rr} typ.	26 ns			
T _J max.	175 °C			
Diode variation	Common cathode			

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification





 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTIONS / APPLICATIONS

VS-CPU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

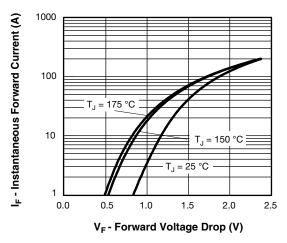
ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Repetitive peak reverse voltage	V_{RRM}		600	V
Average rectified forward current per leg	I _{F(AV)}	T _C = 131 °C	30	
Non-repetitive peak surge current per leg	I _{FSM}	T_C = 25 °C, t_p = 8.3 ms half sine wave; connecting two anode pins	250 A	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

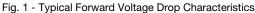
ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage V _F	V	I _F = 30 A	-	1.4	1.75	V	
	I _F = 30 A, T _J = 150 °C	-	1.1	1.4			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	0.02	30		
		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	30	200	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	20	-	pF	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	26	-	
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 30 A dI _F /dt = -200 A/μs V _R = 200 V	-	42	-	ns
		T _J = 125 °C		-	100	-	
Peak recovery current		T _J = 25 °C		-	5	-	A
	I _{RRM}	T _J = 125 °C		-	10	-	
Reverse recovery charge	0	T _J = 25 °C		-	125	-	nC
	Q _{rr}	T _J = 125 °C		-	580	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	IBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	0.7	1	
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	6.0	-	g
vveignt			-	0.21	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AD 3L	CPU6006LH			





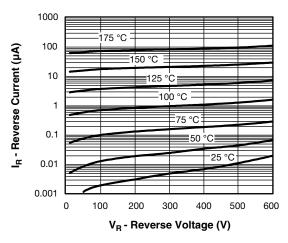


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

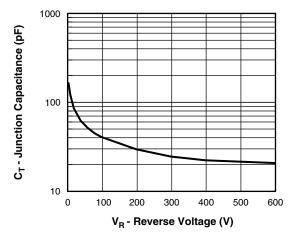


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

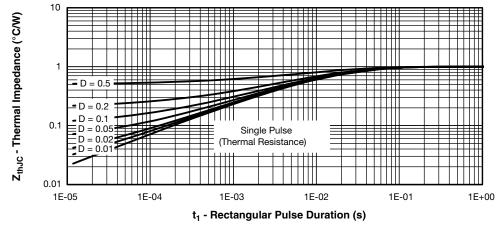


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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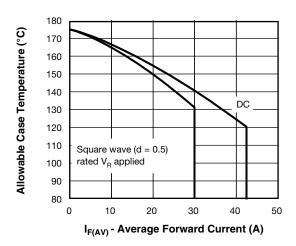


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

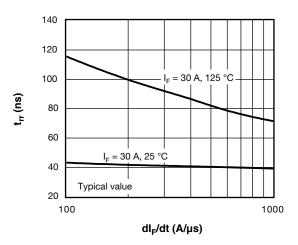


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

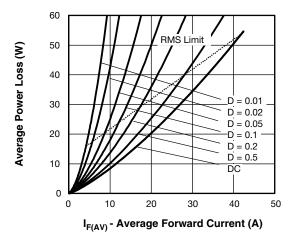


Fig. 6 - Forward Power Loss Characteristics

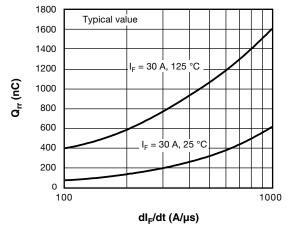
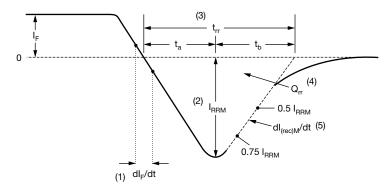


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RBM} and 0.50 I_{RBM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

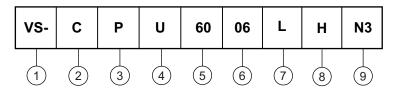
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Circuit configuration:

C = common cathode

- **3** P = TO-247
- U = ultrafast recovery time
- 5 Current code (60 = 2 x 30 A)
- 6 Voltage code (06 = 600 V)
- 7 L = long lead
- 8 H = AEC-Q101 qualified
- 9 Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-CPU6006LHN3	25	500	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS			
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626	
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007	



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